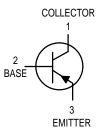
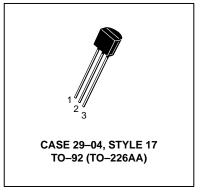
Amplifier Transistors PNP Silicon



BC307 BC307B BC307C BC308C



MAXIMUM RATINGS

Rating	Symbol	BC307, B, C	BC308C	Unit
Collector-Emitter Voltage	VCEO	-45	-25	Vdc
Collector-Base Voltage	Vсво	-50	-30	Vdc
Emitter-Base Voltage	VEBO	-5.0		Vdc
Collector Current — Continuous	IC	-100		mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	350 2.8		mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.0 8.0		Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{Stg}	-55 to +150		°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	357	°C/W
Thermal Resistance, Junction to Case	R_{θ} JC	125	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•				
Collector-Emitter Breakdown Voltage (I _C = -2.0 mAdc, I _B = 0)	BC307,B,C BC308C	V(BR)CEO	-45 -25	_ _	_ _	Vdc
Emitter-Base Breakdown Voltage (I _E = -100 μAdc, I _C = 0)	BC307,B,C BC308C	V(BR)EBO	-5.0 -5.0	_ _	_ _	Vdc
Collector–Emitter Leakage Current (VCES = -50 V, VBE = 0) (VCES = -30 V, VBE = 0) (VCES = -50 V, VBE = 0) TA = 125°C (VCES = -30 V, VBE = 0) TA = 125°C	BC307,B,C BC308C BC307,B,C BC308C	ICES	_ _ _ _	-0.2 -0.2 -0.2 -0.2	-15 -15 -4.0 -4.0	nAdc μA

BC307 BC307B BC307C BC308C

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS						
DC Current Gain (I _C = -10μ Adc, V _{CE} = -5.0 Vdc)	BC307B BC307C/308C	hFE	_ _	150 270	_	_
$(I_C = -2.0 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$	BC307 BC307B/308B BC307C/308C		120 200 420	— 290 500	800 460 800	
$(I_C = -100 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc})$	BC307B BC307C/308C		_ _	180 300	_	
Collector-Emitter Saturation Voltage ($I_C = -10 \text{ mAdc}$, $I_B = -0.5 \text{ mAdc}$) ($I_C = -10 \text{ mAdc}$, $I_B = \text{see Note 1}$) ($I_C = -100 \text{ mAdc}$, $I_B = -5.0 \text{ mAdc}$)		VCE(sat)	_ _ _	-0.10 -0.30 -0.25	-0.3 -0.6 	Vdc
Base-Emitter Saturation Voltage ($I_C = -100 \text{ mAdc}$, $I_B = -0.5 \text{ mAdc}$) ($I_C = -100 \text{ mAdc}$, $I_B = -5.0 \text{ mAdc}$)		V _{BE} (sat)	_ _ _	-0.7 -1.0	_	Vdc
Base–Emitter On Voltage (I _C = -2.0 mAdc, V _{CE} = -5.0 Vdc)		VBE(on)	-0.55	-0.62	-0.7	Vdc
DYNAMIC CHARACTERISTICS						•
Current-Gain — Bandwidth Product $(I_C = -10 \text{ mAdc}, V_{CE} = -5.0 \text{ Vdc}, f = 100 \text{ MHz})$	BC307,B,C BC308C	fΤ	_ _	280 320	_	MHz
Common Base Capacitance ($V_{CB} = -10 \text{ Vdc}$, $I_{C} = 0$, $f = 1.0 \text{ MHz}$)		C _{cbo}	_	_	6.0	pF
Noise Figure (IC = -0.2 mAdc, VCE = -5.0 Vdc, RS = 2.0 k Ω , f = 1.0 kHz)	BC307,B,C	NF	_	2.0	10	dB
(IC = -0.2 mAdc, VCE = -5.0 Vdc, RS = 2.0 k Ω , f = 1.0 kHz, f = 200 Hz)	BC308C		_	2.0	10	

TYPICAL CHARACTERISTICS

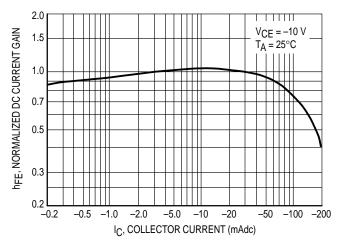


Figure 1. Normalized DC Current Gain

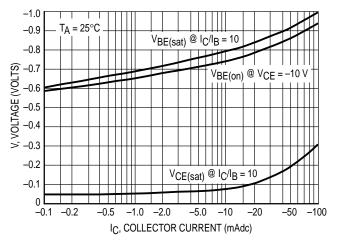


Figure 2. "Saturation" and "On" Voltages

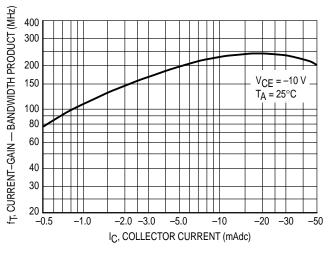


Figure 3. Current-Gain — Bandwidth Product

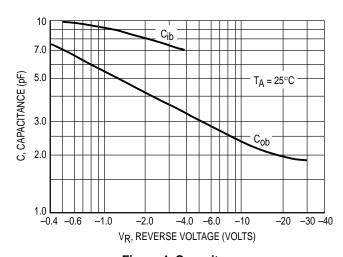


Figure 4. Capacitances

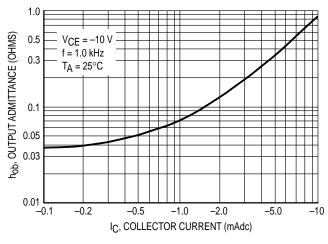


Figure 5. Output Admittance

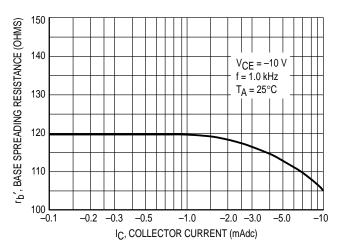
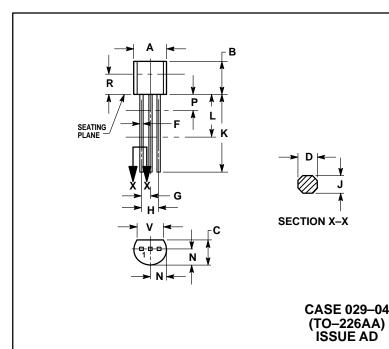


Figure 6. Base Spreading Resistance

PACKAGE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L. DIMENSION F APPLIES BETWEEN F AND L.
 DIMENSION D AND J APPLY BETWEEN L AND K
 MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
V	0.135		3 43	

STYLE 17: PIN 1. COLLECTOR

- 3. EMITTER

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typical parameters, including or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fee arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and (M) are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 303-675-2140 or 1-800-441-2447

 $\textbf{Mfax}^{\text{\tiny{TM}}}\text{: RMFAX0@email.sps.mot.com} - \text{TOUCHTONE } 602-244-6609$

JAPAN: Nippon Motorola Ltd.: SPD, Strategic Planning Office, 4-32-1, Nishi-Gotanda, Shinagawa-ku, Tokyo 141, Japan. 81-3-5487-8488

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, US & Canada ONLY 1-800-774-1848 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298

INTERNET: http://motorola.com/sps



BC307/D

Mfax is a trademark of Motorola. Inc.